



1.5A, 50V - 1000V Standard Rectifier

FEATURES

- Glass passivated chip junction
- High efficiency, Low V_F
- High current capability
- High surge current capability
- Low power loss
- RoHS Compliant
- Halogen-free according to IEC 61249-2-21

APPLICATIONS

- DC to DC converter
- Switching mode converters and inverters
- General purpose

MECHANICAL DATA

- Case: DO-204AC (DO-15)
- Molding compound meets UL 94V-0 flammability rating
- Terminal: Pure tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 1A whisker test
- Polarity: Indicated by cathode band
- Weight: 0.400g (approximately)

KEY PARAMETERS					
PARAMETER	VALUE	UNIT			
I _F	1.5	Α			
V_{RRM}	50 - 1000	V			
I _{FSM}	50	Α			
T _{J MAX}	150	°C			
Package	DO-204AC (DO-15)				
Configuration	Single die				







		1N							
PARAMETER	SYMBOL	5391	5392	5393	5395	5397	5398	5399	UNIT
		G-T							
Marking code on the device		1N 5391G	1N 5392G	1N 5393G	1N 5395G	1N 5397G	1N 5398G	1N 5399G	
Repetitive peak reverse voltage	V_{RRM}	50	100	200	400	600	800	1000	V
Reverse voltage, total rms value	$V_{R(RMS)}$	35	70	140	280	420	560	700	V
Forward current	I _F	1.5					Α		
Surge peak forward current, 8.3ms single half sine wave superimposed on rated load	I _{FSM}	50					А		
Junction temperature	T_J	-55 to +150					°C		
Storage temperature	T _{STG}	-55 to +150					°C		



THERMAL PERFORMANCE					
PARAMETER	SYMBOL	TYP	UNIT		
Junction-to-ambient thermal resistance	R _{eJA}	65	°C/W		

ELECTRICAL SPECIFICATIONS (T _A = 25°C unless otherwise noted)							
PARAMETER		CONDITIONS	SYMBOL	TYP	MAX	UNIT	
	1N5391G-T 1N5392G-T		V _F	-	1.1	V	
Forward voltage ⁽¹⁾	1N5393G-T 1N5395G-T 1N5397G-T 1N5398G-T 1N5399G-T			-	1.0	V	
Reverse current @ rated V _R ⁽²⁾		$T_J = 25^{\circ}C$		-	5	μA	
		T _J = 125°C	- I _R	-	100	μA	
Junction capacitance		$1MHz, V_R = 4.0V$	CJ	15	-	pF	

Notes:

- 1. Pulse test with PW = 0.3ms
- 2. Pulse test with PW = 30ms

ORDERING INFORMATION					
ORDERING CODE ⁽¹⁾	PACKAGE	PACKING			
1N539xG-T	DO-204AC (DO-15)	3,500 / Tape & Reel			
1N539xG-T A0G	DO-204AC (DO-15)	1,500 / Ammo box			

Notes:

1. "x" defines voltage from 50V (1N5391G-T) to 1000V (1N5399G-T)



CHARACTERISTICS CURVES

(T_A = 25°C unless otherwise noted)

Fig.1 Forward Current Derating Curve

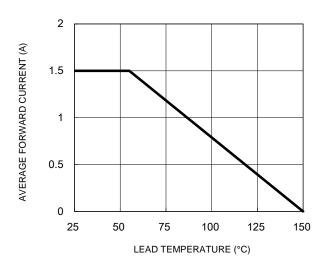


Fig.3 Typical Reverse Characteristics

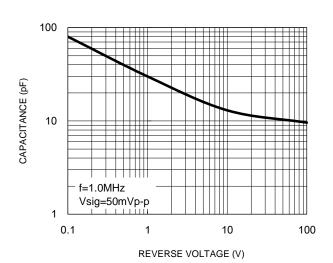
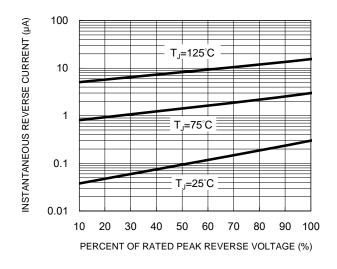


Fig.2 Typical Junction Capacitance

Fig.4 Typical Forward Characteristics



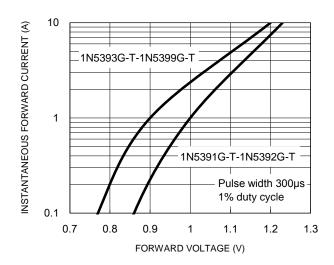
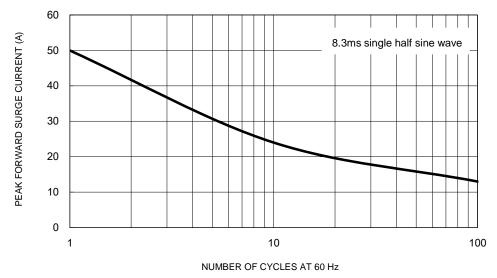


Fig.5 Maximum Non-Repetitive Forward Surge Current

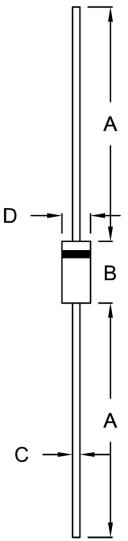






PACKAGE OUTLINE DIMENSIONS





DIM	DIM. Unit (m		nm) Unit (inch)		
	Min.	Max.	Min.	Max.	
А	25.40	-	1.000	-	
В	5.80	7.60	0.228	0.299	
С	0.70	0.90	0.028	0.035	
D	2.60	3.60	0.102	0.142	

MARKING DIAGRAM



P/N = Marking Code G = Green Compound

YWW = Date Code F = Factory Code



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